

# RGTH50TS65GC13

650V 25A Field Stop Trench IGBT

V <sub>CES</sub>	650V
I <sub>C(100°C)</sub>	25A
V <sub>CE(sat) (Typ.)</sub>	1.6V
P <sub>D</sub>	174W

### Features

- 1) Low Collector Emitter Saturation Voltage
- 2) High Speed Switching
- 3) Low Switching Loss & Soft Switching
- 4) Pb free Lead Plating ; RoHS Compliant

## Applications

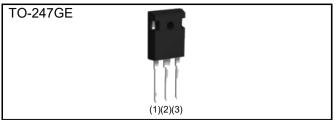
PFC

UPS

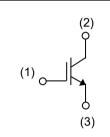
**Power Conditioner** 

IH

# Outline



#### Inner Circuit





#### Packaging Specifications

	Packaging	Tube
	Reel Size (mm)	-
Tupo	Tape Width (mm)	-
Туре	Basic Ordering Unit (pcs)	600
	Packing code	C13
	Marking	RGTH50TS65

# •Absolute Maximum Ratings (at T<sub>C</sub> = 25°C unless otherwise specified)

Parameter		Symbol	Value	Unit
Collector - Emitter Voltage		V <sub>CES</sub>	650	V
Gate - Emitter Voltage		V <sub>GES</sub>	±30	V
Collector Current	T <sub>C</sub> = 25°C	Ι <sub>C</sub>	50	А
Collector Current	T <sub>C</sub> = 100°C	Ι <sub>C</sub>	25	А
Pulsed Collector Current		I <sub>CP</sub> <sup>*1</sup>	100	А
Power Dissinction	T <sub>C</sub> = 25°C	P <sub>D</sub>	174	W
Power Dissipation	T <sub>C</sub> = 100°C	P <sub>D</sub>	87	W
Operating Junction Temperature		Tj	-40 to +175	°C
Storage Temperature		T <sub>stg</sub>	–55 to +175	°C

\*1 Pulse width limited by T<sub>jmax.</sub>

## RGTH50TS65GC13

#### •Thermal Resistance

Parameter	Symbol	Values		Max. Unit	Unit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal Resistance IGBT Junction - Case	$R_{\theta(j\text{-}c)}$	-	-	0.86	°C/W

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Symbol	Conditions	Values			Unit	
Symbol	Conditions	Min.	Тур.	Max.	Unit	
BV <sub>CES</sub>	I <sub>C</sub> = 10μΑ, V <sub>GE</sub> = 0V	650	-	-	V	
I <sub>CES</sub>	V <sub>CE</sub> = 650V, V <sub>GE</sub> = 0V	-	-	10	μA	
I <sub>GES</sub>	V <sub>GE</sub> = ±30V, V <sub>CE</sub> = 0V	-	-	±200	nA	
V <sub>GE(th)</sub>	V <sub>CE</sub> = 5V, I <sub>C</sub> = 17.5mA	4.5	5.5	6.5	V	
V <sub>CE(sat)</sub>		-	1.6 2 1	2.1	V	
	I <sub>CES</sub> I <sub>GES</sub> V <sub>GE(th)</sub>	$BV_{CES} = 10\mu A, V_{GE} = 0V$ $I_{CES} = 0V = 0V$ $I_{GES} = 0V = 0V$ $V_{GE} = 0V = 0V$ $V_{GE} = 0V = 0V$ $V_{GE} = 0V = 0V$ $V_{CE} = 0V = 0V$ $I_{CE} = 0V = 0V$ $I_{CE} = 0V = 0V$ $I_{CE} = 0V = 0V$	Min.       Min. $BV_{CES}$ $I_C = 10\mu A$ , $V_{GE} = 0V$ 650 $I_{CES}$ $V_{CE} = 650V$ , $V_{GE} = 0V$ - $I_{GES}$ $V_{GE} = 430V$ , $V_{CE} = 0V$ - $V_{GE(th)}$ $V_{CE} = 5V$ , $I_C = 17.5mA$ 4.5 $V_{CE(sat)}$ $I_C = 25A$ , $V_{GE} = 15V$ - $V_{CE(sat)}$ $T_j = 25^{\circ}C$ -	Symbol         Conditions         Min.         Typ. $BV_{CES}$ $I_{C} = 10\mu A$ , $V_{GE} = 0V$ 650         - $I_{CES}$ $V_{CE} = 650V$ , $V_{GE} = 0V$ -         - $I_{GES}$ $V_{CE} = 650V$ , $V_{GE} = 0V$ -         - $I_{GES}$ $V_{GE} = \pm 30V$ , $V_{CE} = 0V$ -         - $V_{GE(th)}$ $V_{CE} = 5V$ , $I_{C} = 17.5mA$ 4.5         5.5 $V_{CE(sat)}$ $T_{j} = 25^{\circ}C$ -         1.6	Symbol         Conditions         Min.         Typ.         Max. $BV_{CES}$ $I_C = 10\mu A$ , $V_{GE} = 0V$ 650         -         - $I_{CES}$ $I_C = 10\mu A$ , $V_{GE} = 0V$ 650         -         - $I_{CES}$ $V_{CE} = 650V$ , $V_{GE} = 0V$ -         -         10 $I_{GES}$ $V_{CE} = 650V$ , $V_{GE} = 0V$ -         -         10 $I_{GES}$ $V_{GE} = 430V$ , $V_{CE} = 0V$ -         -         ±200 $V_{GE(th)}$ $V_{CE} = 5V$ , $I_C = 17.5mA$ 4.5         5.5         6.5 $V_{CE(sat)}$ $I_C = 25A$ , $V_{GE} = 15V$ -         1.6         2.1	

# ●IGBT Electrical Characteristics (at T<sub>j</sub> = 25°C unless otherwise specified)

Demonster	O maked		Values			11-14
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input Capacitance	$C_{ies}$	V <sub>CE</sub> = 30V	-	1410	-	
Output Capacitance	C <sub>oes</sub>	V <sub>GE</sub> = 0V	-	57	-	pF
Reverse Transfer Capacitance	C <sub>res</sub>	f = 1MHz	-	22	-	
Total Gate Charge	$Q_g$	V <sub>CE</sub> = 300V	-	49	-	
Gate - Emitter Charge	$Q_{ge}$	I <sub>C</sub> = 25A	-	15	-	nC
Gate - Collector Charge	$Q_{gc}$	V <sub>GE</sub> = 15V	-	19	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 25A, V <sub>CC</sub> = 400V	-	27	-	
Rise Time	t <sub>r</sub>	V <sub>GE</sub> = 15V, R <sub>G</sub> = 10Ω	-	38	-	20
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 25°C	-	94	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	50	-	
Turn - on Delay Time	t <sub>d(on)</sub>	I <sub>C</sub> = 25A, V <sub>CC</sub> = 400V	-	27	-	
Rise Time	t <sub>r</sub>	V <sub>GE</sub> = 15V, R <sub>G</sub> = 10Ω	-	38	-	20
Turn - off Delay Time	$t_{d(off)}$	T <sub>j</sub> = 175°C	-	107	-	ns
Fall Time	t <sub>f</sub>	Inductive Load	-	65	-	
		I <sub>C</sub> = 100A, V <sub>CC</sub> = 520V				
Reverse Bias Safe Operating Area	RBSOA	V <sub>P</sub> = 650V, V <sub>GE</sub> = 15V	FU	LL SQUA	RE	-
		R <sub>G</sub> = 60Ω, T <sub>j</sub> = 175°C				

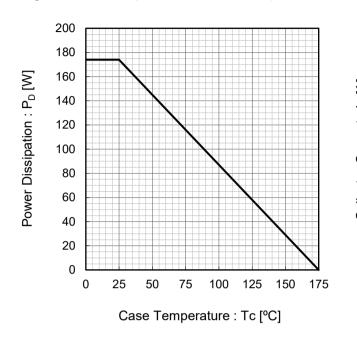
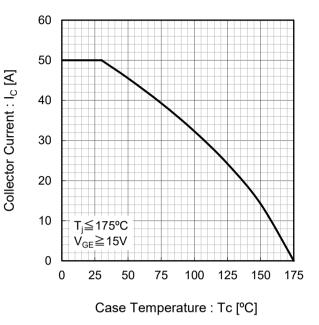


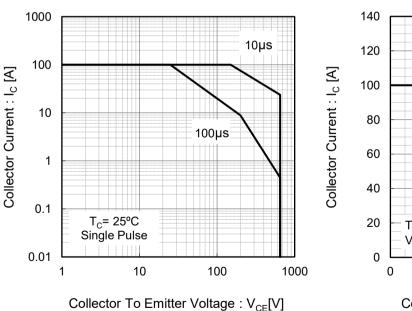
Fig.1 Power Dissipation vs. Case Temperature

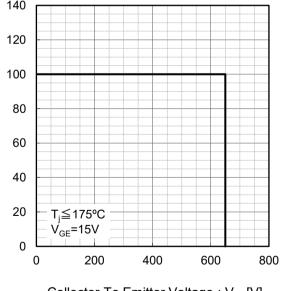
Fig.2 Collector Current vs. Case Temperature



# Fig.3 Forward Bias Safe Operating Area

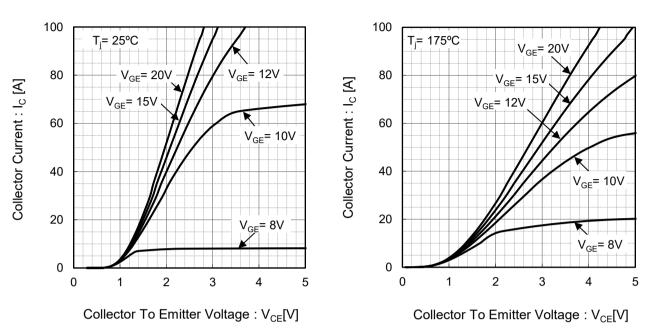
Fig.4 Reverse Bias Safe Operating Area





Collector To Emitter Voltage :  $V_{CE}[V]$ 

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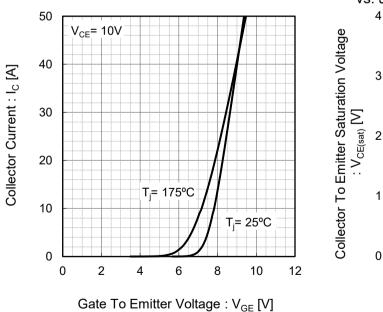


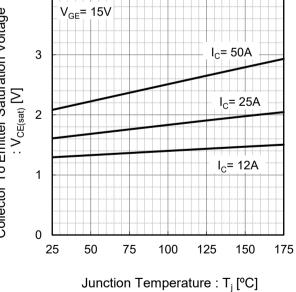
#### Fig.5 Typical Output Characteristics

#### Fig.7 Typical Transfer Characteristics

Fig.8 Typical Collector To Emitter Saturation Voltage vs. Junction Temperature

Fig.6 Typical Output Characteristics





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Fig.10 Typical Collector To Emitter Saturation Voltage

#### •Electrical Characteristic Curves

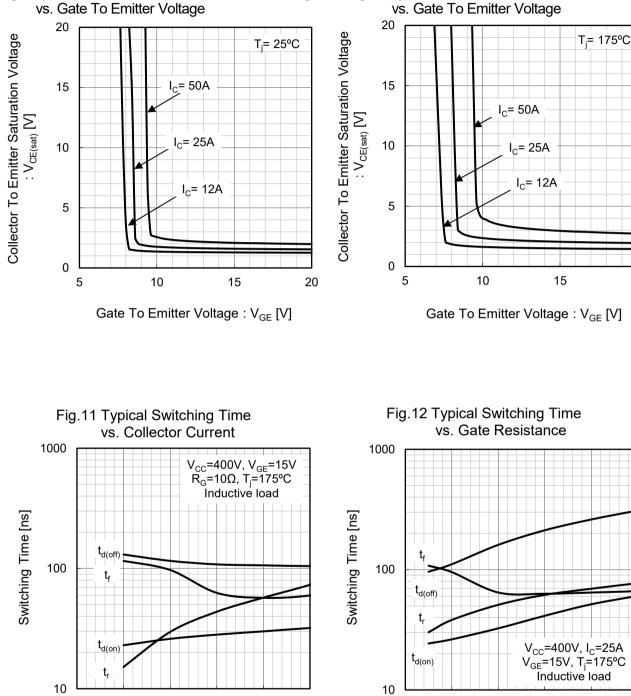


Fig.9 Typical Collector To Emitter Saturation Voltage vs. Gate To Emitter Voltage

Gate Resistance :  $R_G[\Omega]$ 

30

40

50

20

10

0

0

10

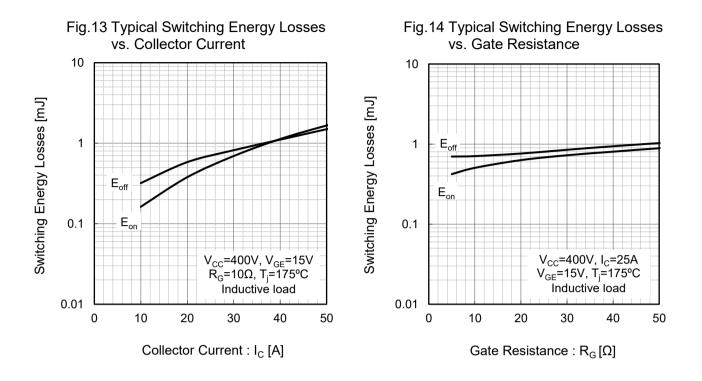
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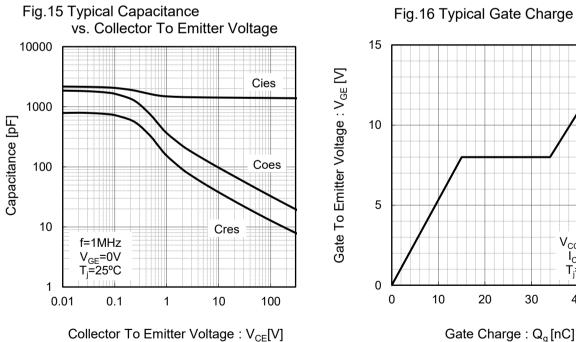
Collector Current : I<sub>C</sub> [A]

30

40

50





V<sub>CC</sub>=300V

Ĭ<sub>c</sub>=25A

Ti=25⁰C

50

40

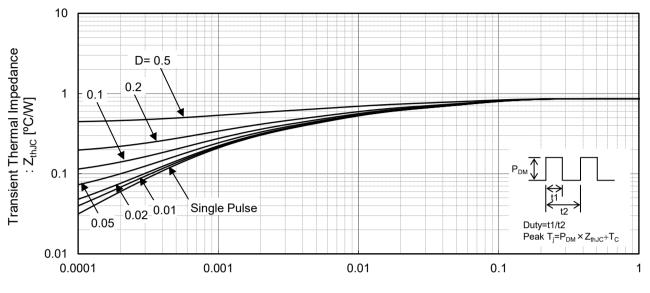


Fig.17 IGBT Transient Thermal Impedance

Pulse Width : t1[s]

### ●Inductive Load Switching Circuit and Waveform

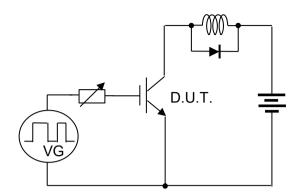
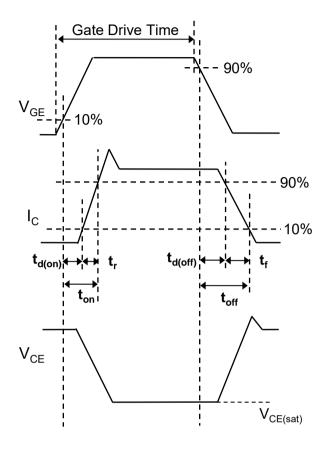
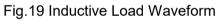


Fig.18 Inductive Load Circuit





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